

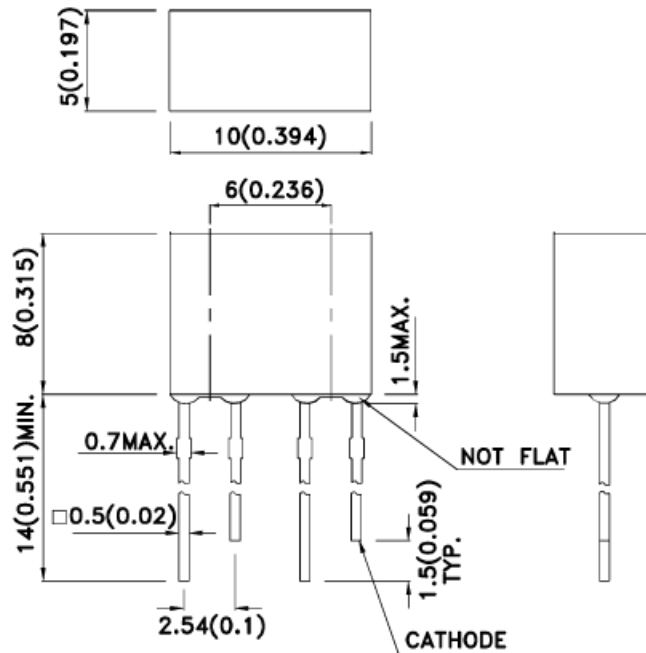
Features

- Uniform light emitting area.
- Easily mounted on P.C. boards or industry standard sockets.
- Flush mountable.
- Excellent on/off contrast.
- Can be used with panels and legend mounts.
- Mechanically rugged.
- Bottom surface of epoxy is not flat.
- RoHS compliant.

Description

The Hyper Red source color devices are made with Al-GaN on GaAs substrate Light Emitting Diode.

Package Dimensions



Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is ± 0.25 (0.01") unless otherwise noted.
3. Lead spacing is measured where the leads emerge from the package.
4. The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.



Selection Guide

| Part No. | Dice | Lens Type | Iv (mcd) [2] @ 20mA | | Viewing Angle [1] |
|---------------|---------------------|--------------|------------------------|------|----------------------|
| | | | Min. | Typ. | 2θ1/2 |
| L-835/2SURDTK | Hyper Red (AlGaInP) | Red Diffused | 80 | 250 | 120° |

Notes:

1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value.
2. Luminous intensity/ luminous Flux: +/-15%.

Electrical / Optical Characteristics at TA=25°C

| Symbol | Parameter | Device | Typ. | Max. | Units | Test Conditions |
|--------------------|--------------------------|-----------|------|------|-------|---------------------------|
| λpeak | Peak Wavelength | Hyper Red | 650 | | nm | I _F =20mA |
| λD [1] | Dominant Wavelength | Hyper Red | 630 | | nm | I _F =20mA |
| Δλ1/2 | Spectral Line Half-width | Hyper Red | 28 | | nm | I _F =20mA |
| C | Capacitance | Hyper Red | 35 | | pF | V _F =0V;f=1MHz |
| V _F [2] | Forward Voltage | Hyper Red | 1.95 | 2.5 | V | I _F =20mA |
| I _R | Reverse Current | Hyper Red | | 10 | uA | V _R = 5V |

Notes:

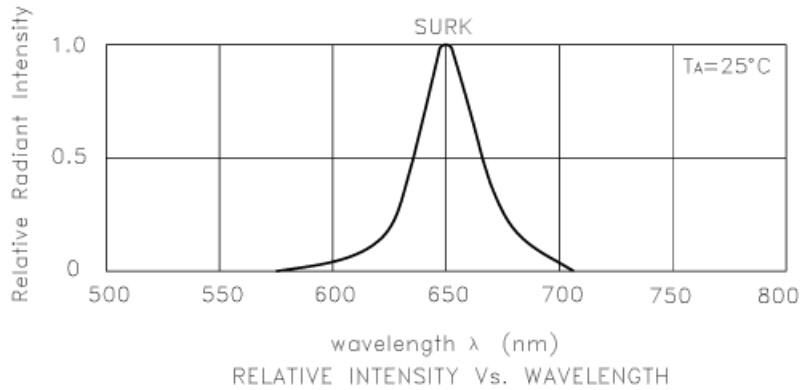
1. Wavelength: +/-1nm.
2. Forward Voltage: +/-0.1V.

Absolute Maximum Ratings at TA=25°C

| Parameter | Hyper Red | Units |
|-------------------------------|---------------------|-------|
| Power dissipation | 75 | mW |
| DC Forward Current | 30 | mA |
| Peak Forward Current [1] | 185 | mA |
| Reverse Voltage | 5 | V |
| Operating/Storage Temperature | -40°C To +85°C | |
| Lead Solder Temperature [2] | 260°C For 3 Seconds | |
| Lead Solder Temperature [3] | 260°C For 5 Seconds | |

Notes:

1. 1/10 Duty Cycle, 0.1ms Pulse Width.
2. 2mm below package base.
3. 5mm below package base.



Hyper Red

L-835/2SURDTK

